

Department: ناوی بەش	Physsics department بەشی فیزییا				
College : کۆلیج	College of science				
Student : خوێندکار	3rd degree		Bochler of Science (BS.c)		Academic profile
Specialty : بەسپۆری	زانستی فیزیایی				
Subject : بایەت	Electronics				
Language of instruction English	زمانی ووتنەوهی وانه	Language of instruction زمانی ووتنەوهی وانه	Lecture وانه	Activity حالاك	L/P تاقیگه
			8	6	8
Status item دۆخی وانه که	Semestr وهرز	Form of assessment شیوازی هەنسه‌نگاندن	Code ECTS کۆدی وانه	:ECTS For the item ژماره‌ی ECTS بۆ وانه که	
Specialty subject بایه‌تی ب‌سپۆری	2nd دووه‌م	Exam تاقیکردنه‌وه	UOH102603	6	
Title Surname Name Responsible for the item: نازناوی زانستی و ناوی مامۆستای وانه	Lecturer , Mr. Farhad Muhsin Mahmood				
Course Book :SUBJECT MATTER					
Objectives of the subject: ئامانجه‌کانی وانه که					
Objec. 1 ئامانجی ١	1. Have Brief Idea about Electricity and Electronics				
Objec. 2 ئامانجی ٢	2. Understanding the meaning of electronic tools and their applications.				
Objec. 3 ئامانجی ٣	3. To learn about semiconductor which is the most important sub material in the electronic and transistors and the basic block of Ics.				
Objec. 4 ئامانجی ٤	4. Know and try to Make a intelligent and techno-logistic day by electronic.				
Prerequisites in terms of knowledge, skills and other competencies: داواکارییه سه‌ره‌کییه‌کان له‌رووی زانین و لێهاتووی و توانا‌کانی دیکه					
knowl. 1 زانینی ١	Semiconductor, Electron transition , Electrical Conductivity of Semiconductors, Physical Properties of Semiconductors, Binary digit and Ics working				
Learning outcomes (for the subject chosen in line 7) : ده‌رته‌نجامه‌کانی فێرکردن					
Learning Outcome ده‌رته‌نجامی فێرکردن	Symbol سیمبول	Description وورده‌کاری (kind of activities)	Reference to the directional effects of education ئامازهدان له‌سه‌ر کاریگه‌ری ئاراسته‌کردنی		
LO1	1_L02	Having successfully completed this module, you will be able to demonstrate knowledge and understanding of: Transistors Types			
LO2	1_L05	BJT transistors, its specifications and working principle.			
LO3	1_L06	being continoue with BJT for more details			
LO4	1_S04	Start to teaching FETs, their working, specifications and application			
LO5	1_S06	Digital Logic Gates, their priciple of working, their specification and applications			
Program content					
Form of classes له‌کلاسه‌وه	Topics of lectures بایه‌ته‌کانی وانه که			Number of Hours ژماره‌ی کاژمیره‌کان	

Chapter One	Chapter One: Bipolar Junction Transistors (BJT)-1 1. Historical review of Transistors 2. Bipolar junction transistor introduction 3. BJT operation modes 4. PNP transistor 5. NPN transistor 6. Transistor construction 7. Transistor currents	7
Chapter Two	Chapter Two: Bipolar Junction Transistors (BJT)-2 1. Types of transistor configuration 2. Common base configuration 3. Common emitter configuration 4. Common collector configuration	10
Chapter Three	Chapter Three: Field Effect transistors 1. Review of BJT 2. Introduction (FET) 3. Junction Field Effect Transistor (JFET) 4. Working of JFET 5. Characteristics of JFET 6. Metal Oxide Semiconductor Transistors (MOSFET) 7. Modes of Biasing for Transistors 8. Application of Transistor 9. IGBT & Comparison Table 10. Internal Structure of IGBT 11. Working of IGBT 12. Type of IGBT 13. Switching Characteristics of IGBT	8
Chapter Four	Chapter Four: Power Amplifier 1. Introduction, Series-Fed Class A Amplifier, Transformer-Coupled Class A Amplifier, Transformer-Coupled Class A Amplifier, Class B Amplifier Circuits	2. 3. 4. 5. 8
Chapter Five	Chapter Five: 1. Introduction 2. Classification of Integrated Circuits 3. Digital Logic States 4. TTL and CMOS Logic Levels 5. Digital Logic States 6. Digital Logic "AND" Gate 7. Digital Logic "OR" Gate 8. Digital Logic "NOT" Gate 9. Digital Logic "NAND" Gate 10. Digital Logic "NOR" Gate , 11. Digital Logic "EX-OR" Gate, 12. Digital Logic "EX-NOR" Gate, 13. Review	6
	Topics of exercises (Activity) بایه‌ته کانی هه‌نسه‌نگاندن	Number of Hours ژماره‌ی کارژمیره‌کان
Exe. 1 هه‌نسه‌نگاندنی ١	Chapter One	2
Exe. 2 هه‌نسه‌نگاندنی ٢	Chapter Two	4
Exe. 3 هه‌نسه‌نگاندنی ٣	Chapter Three	2
Exe. 4 هه‌نسه‌نگاندنی ٤	Chapter Four	2
Exe. 5 هه‌نسه‌نگاندنی ٥	Chapter Five	2
Exe. 6		
	Topics in seminars (or other classes) بایه‌ته کانی سیمینار	Number of Hours ژماره‌ی کارژمیره‌کان
Sem. 1	Topics will be confirmed prior to the seminar	
Sem. 2	Topics will be confirmed prior to the seminar	
	Subjects of laboratories بایه‌ته کانی تاقیگه	Number of Hours ژماره‌ی کارژمیره‌کان
Lab. 1 تاقیگه ١	Experiment 1 : Capacitor filtering	3
Lab. 2 تاقیگه ٢	Experiment 2 : Voltage Doubler	3
Lab. 3 تاقیگه ٣	Experiment 3: BJT Characteristics	3
Lab. 4 تاقیگه ٤	Experiment 4: FET Characyeristics	3
Lab. 5 تاقیگه ٥	Experiment 5: IGBT Characteristics	3
Lab. 6 تاقیگه ٦	Experiment 6: Digital logic AND, OR, NAND, NOR	3

Lab. 7 تاقیگه 7	Experiment 7: Digital logic Mixed Objects of the experiments	3	
Lab. 8 تاقیگه 8		3	
Didactic methods رینگاکی وانه ووتنهوه		Comments کۆمینت	
D.M. 1 رینگاکی 1	Vedio learning method	Vedio , Powerpoint , Other	
D.M.2 رینگاکی 2	E-intro lecture, laboratory or auditorium exercises;	Google Meet , Univrsity Porta	
D.M. 3 رینگاکی 3	Usin gstudent-Centred Approch	Online meet	
D.M.4 رینگاکی 4	PBL		
Student workload کۆششی خویندکار			
Form of activity له جالاکییه کانهوه		Mean number of hours to complete a given activity نیهۆندی کارمهیه کان بۆ تهواو کردنی جالاکییه کی دیاری کراو	
Contact hours with lead subjects کارمهیه کانی په یهۆندی له گه ل بابه ته سه ره کییه کدا		66	
Preparing for the lab or exercises تاماده بوون له تاقیگه و نه انجامدانی جالاکی		50	
Preparing to pass ئامده کانی بۆ ده رجوون		20	
Work in the library کار کردن له کتبخانه دا		0	
Preparing the project کار کردن له بۆقه		26	
Sum: کۆ		162	
ECTS sums for obligatory subjects (PO, PP and PK)		PO: 26,25, PP: 28 PK: 42 SUM: 19	
Literature or Bibliography			
primary: سه ره کی			
Semiconductor Physics			
Further: لاوه کی یا خوود زیاده			
https://www.electronicshub.org/applications-of-diodes/ https://www.digikey.com/en/maker/blogs/zener-diode-basic-operation-and-applications https://electronics.howstuffworks.com/led4.htm https://www.physics-and-radio-electronics.com/electronic-devices-and-circuits/semiconductor-diodes/varactordiode-construction-definition-working.html https://www.electronics-tutorials.ws/transistor/tran_5.html https://www.electronics-tutorials.ws/category/premium Recommended Book: ELECTRONIC DEVICES AND CIRCUIT THEORY , ROBERT BOYLESTAD LOUIS NASHESKY Foundations of Analog and Digital Electronic Circuits , anant agarwal Department of Electrical Engineering and Computer Science, Massachusetts Institute of Technology ,jeffrey h.lang Department of Electrical Engineering and Computer Science, Massachusetts Institute of Technology			
Lead person (academic title, first name, last name, email address) زانباری ستافی نه کادیمی تایبته بهم وانه یه			
1	Lecturer , Mr Farhad Muhsin Mahmood, farhad.mahmood@uoh.edu.iq		
Methods of verification of learning outcomes رینگاکی به ده ست هینانی ده ره نه انجامه کانی فیکردن			
	Passing criterion په وه ره کانی ده رجوون	Verification method رینگاکی به ده ست هینان	Comments کۆمینت
Efekt1	BJT transistors	Activity during classes,	
Efekt2	FET Transistors	Activity during classes,	
Efekt3	IGBT Transistor	Activity during classes,	
Efekt4	Power amplifier	Activity during classes,	
Efekt5	Digital logi gate	Activity during classes,	
Efekt6, Efekt7			
Course requirements داواکاری کۆرس			
mark of the course includes: 1- Pop Activity of the course (50 marks). 2- Midterm exams (20 marks). 3- The final exams (30 marks). The final mark of the course includes 30% of the final mark, 20% of the midterm and %50 of the Activity			
Other useful information about the item هه ره زانباریه کانی دیکه پتویست بۆ بابه ته که			
1	Information on where to read the teaching materials	University website, Portal and online meet	
2	Information about the place of classes	Virtual Head office, information board	

3	Information on the dates of classes (course schedule)	A schedule of classes in accordance with the established schedule
4	Information on the dates and place of consultation of teachers conducting the subject	Virtual Head's office, information board